



#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
100V	700mΩ @ V <sub>GS</sub> = $10$ V	0.70A
100 V	$900 \text{m}\Omega$ @ $V_{GS} = 6.0 \text{V}$	0.62A

## **Description**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

#### **Features and Benefits**

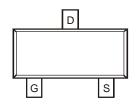
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

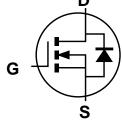
- Case: SOT23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish Annealed over Alloy 42 Leadframe). (§3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)







Top View Pin Configuration



**Equivalent Circuit** 

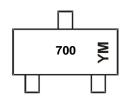
## **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN10H700S-7	SOT23	3,000/Tape & Reel
DMN10H700S-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



700 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

Date Code Hoy												
Year	2015		2016	2017	'	2018	2019	)	2020	2021		2022
Code	С		D	Е		F	G		Н	-		J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	100	V
Gate-Source Voltage	$V_{GSS}$	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	I <sub>D</sub>	0.70 0.56	А
Pulsed Drain Current (10µs Pulse, Duty Cycle ≦1%)	I <sub>DM</sub>	2.5	Α
Maximum Body Diode Continuous Current (Note 6)	I <sub>S</sub>	0.6	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation	(Note 5)	D-	0.4	W
Total Power Dissipation	(Note 6)	P <sub>D</sub>	0.5	۷V
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	303	
Thermal Resistance, Junction to Ambient (Note 6)		$R_{ heta JA}$	239	°C/W
Thermal Resistance, Junction to Case	(Note 6)	$R_{\theta JC}$	88	
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

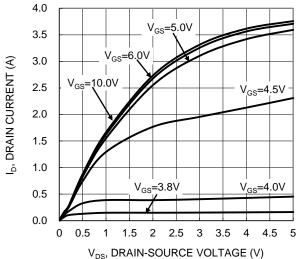
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			1	μΑ	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2.0	2.7	4.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D		540	700	mΩ	$V_{GS} = 10V, I_D = 1.5A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		550	900	11177	$V_{GS} = 6.0V, I_D = 1.0A$	
Diode Forward Voltage	$V_{SD}$		0.9	1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1.5A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	235	_			
Output Capacitance	Coss	_	7	_	pF	$V_{DS} = 50V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	5	_		1 = 1.0Wi 12	
Gate Resistance	Rg	_	1.9		Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Total Gate Charge	$Q_g$	_	4.6	_			
Gate-Source Charge	Q <sub>gs</sub>	_	1.1	_	nC	$V_{DS} = 50V, V_{GS} = 10V,$	
Gate-Drain Charge	$Q_{qd}$	_	1.6	_		I <sub>D</sub> = 1.0A	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	1.1	_		$V_{DS} = 50V, I_{D} = 1.0A,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	5.4	_	ns	$V_{GS} = 10V, R_G = 6.0\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	1.0	_			
Reverse Recovery Time	t <sub>RR</sub>		22	_	ns	1 400\/ L 400\/ L 400\/\/	
Reverse Recovery Charge	Q <sub>RR</sub>		15	_	nC	$V_R = 100V$ , $I_F=1.8A$ , $di/dt=100A/\mu s$	

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
- 7 .Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

## **DMN10H700S**





V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 1. Typical Output Characteristic

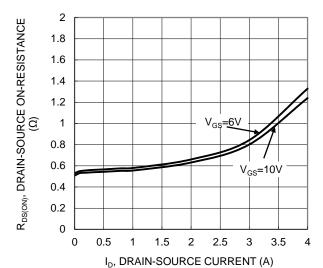


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

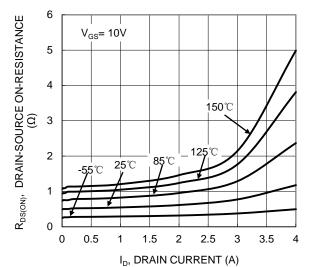
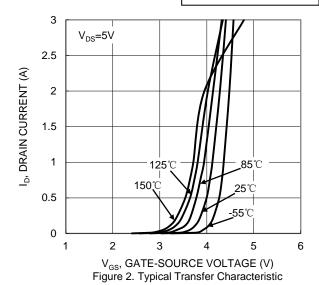


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature



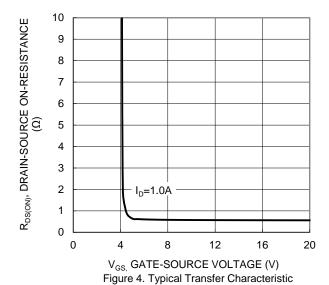
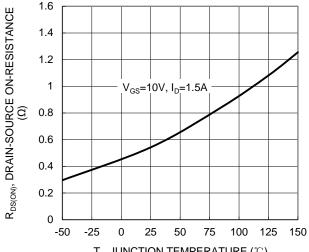


Figure 6. On-Resistance Variation with Junction
Temperature

### **DMN10H700S**





 $T_J$ , JUNCTION TEMPERATURE ( $^{\circ}$ C) Figure 7. On-Resistance Variation with Junction Temperature

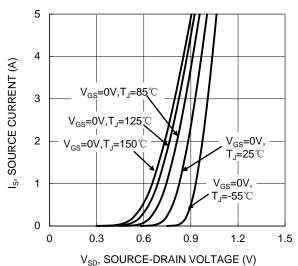


Figure 9. Diode Forward Voltage vs. Current

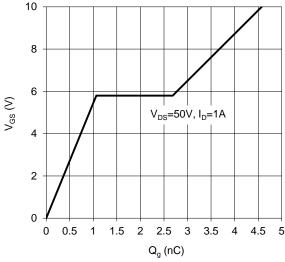


Figure 11. Gate Charge

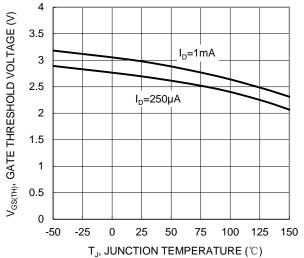
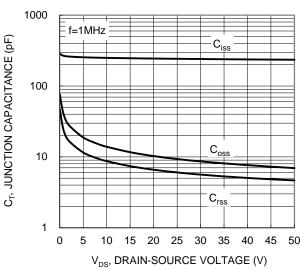


Figure 8. Gate Threshold Variation vs. Junction Temperature



V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 10. Typical Junction Capacitance

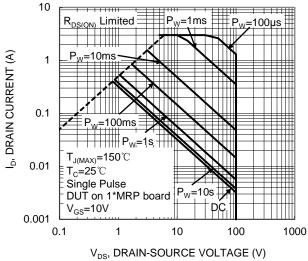


Figure 12. SOA, Safe Operation Area



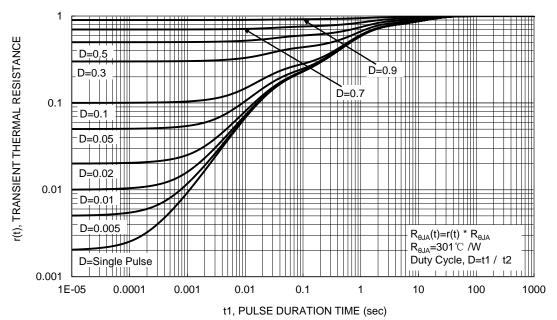


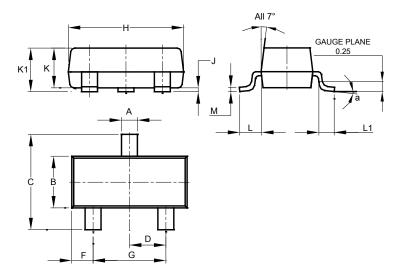
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

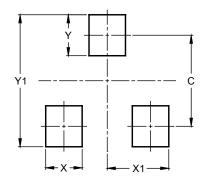


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
H	2.80	3.00	2.90				
7	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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